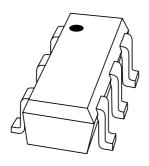
### **DISCRETE SEMICONDUCTORS**

# DATA SHEET



## 1PS88SB48 Schottky barrier diodes

Product specification Supersedes data of 1999 Apr 26 2002 Nov 07





## Schottky barrier diodes

#### 1PS88SB48

#### **FEATURES**

- · Ultra fast switching speed
- · Low forward voltage
- Small SMD package
- · Guard ring protected
- Low capacitance.

#### **APPLICATIONS**

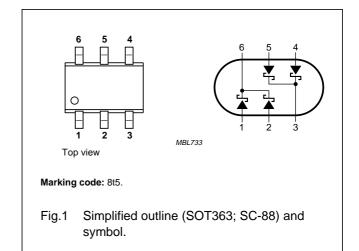
- · High speed switching
- Circuit protection
- · Voltage clamping.

#### **DESCRIPTION**

The 1PS88SB48 consists of two dual Schottky barrier diodes with common cathodes, fabricated in planar technology and encapsulated in the small SOT363 SMD plastic package.

#### **PINNING**

PIN	DESCRIPTION		
1	anode (a1)		
2	anode (a2)		
3	common cathode (k1)		
4	anode (a3)		
5	anode (a4)		
6	common cathode (k2)		



#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT		
Per diode	Per diode						
V <sub>R</sub>	continuous reverse voltage		_	40	V		
I <sub>F</sub>	continuous forward current		_	120	mA		
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	_	120	mA		
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> < 10 ms	_	200	mA		
T <sub>stg</sub>	storage temperature		-65	+150	°C		
Tj	junction temperature		_	150	°C		
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C		

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## Schottky barrier diodes

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#### **ELECTRICAL CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT		
Per diode						
V <sub>F</sub>	continuous forward voltage	see Fig.2				
		I <sub>F</sub> = 1 mA	380	mV		
		I <sub>F</sub> = 10 mA	500	mV		
		I <sub>F</sub> = 40 mA	1	V		
I <sub>R</sub>	continuous reverse current	V <sub>R</sub> = 30 V; note 1; see Fig.3	1	μΑ		
		V <sub>R</sub> = 40 V; note 1; see Fig.3	10	μΑ		
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 0; f = 1 MHz; see Fig.5	5	pF		

#### Note

1. Pulse test:  $t_p = 300 \ \mu s$ ;  $\delta = 0.02$ .

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	416	K/W

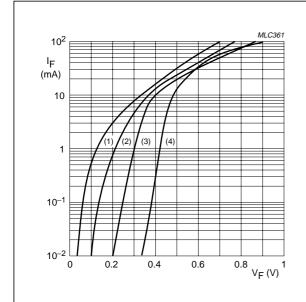
#### Note

1. Refer to SOT363 (SC-88) standard mounting conditions.

## Schottky barrier diodes

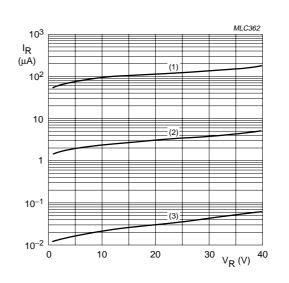
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#### **GRAPHICAL DATA**



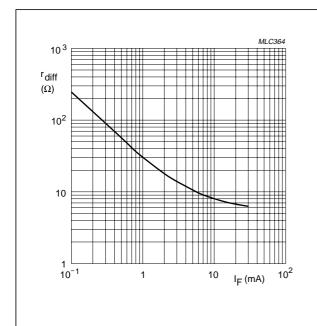
- (1)  $T_{amb} = 150 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \,^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig.2 Forward current as a function of forward voltage; typical values.



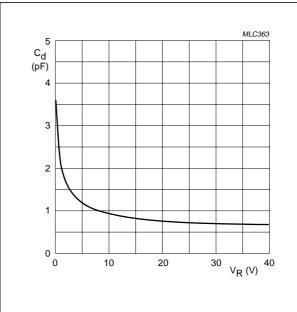
- (1)  $T_{amb} = 150 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .

Fig.3 Reverse current as a function of reverse voltage; typical values.



f = 10 KHz.

Fig.4 Differential forward resistance as a function of forward current; typical values.



f = 1 MHz;  $T_{amb} = 25$  °C.

Fig.5 Diode capacitance as a function of reverse voltage; typical values.

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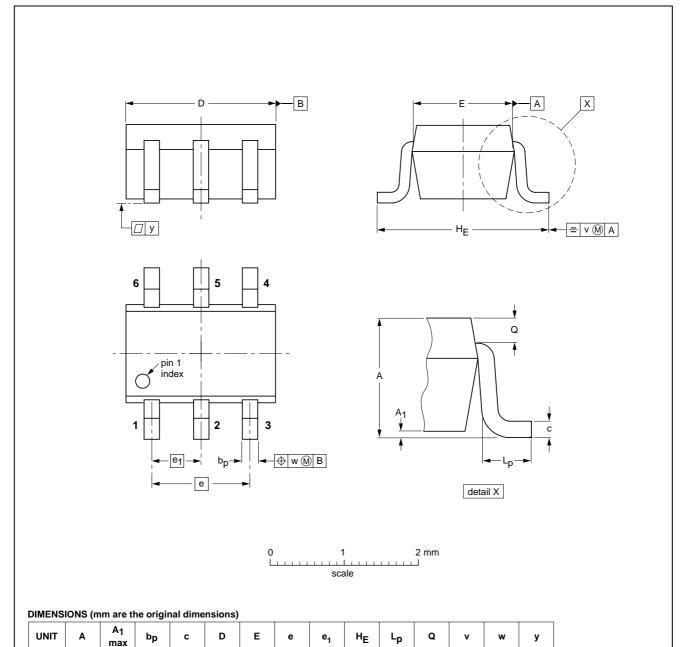
## Schottky barrier diodes

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#### **PACKAGE OUTLINE**

Plastic surface mounted package; 6 leads

**SOT363** 



OUTLINE REFERENCES			RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT363			SC-88		97-02-28

0.65

0.45 0.15 0.25 0.15

0.2

0.1

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0.25 0.10

0.30

0.20

1.1 0.8

mm

0.1

2.2 1.8 1.35 1.15

1.3

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#### Schottky barrier diodes

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LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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## Schottky barrier diodes

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#### **Contact information**

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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Printed in The Netherlands

613514/03/pp8

Date of release: 2002 Nov 07

Document order number: 9397 750 10283

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